

1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT78 (TO-220AB) plastic package intended for use in applications requiring good bidirectional blocking voltage capability, high surge current capability, high junction temperature capability and high thermal cycling performance.

2. Features and benefits

- Good bidirectional blocking voltage capability
- · High junction operating temperature capability
- High surge current capability
- High thermal cycling performance
- Planar passivated for voltage ruggedness and reliability

3. Applications

- Capacitive Discharge Ignition (CDI)
- Crowbar protection
- Inrush protection
- Motor control
- Voltage regulation

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	500	V
V _{RRM}	repetitive peak reverse voltage		-	-	500	V
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms	-	-	132	A
		half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4; Fig. 5</u>	-	-	120	A
Tj	junction temperature		-	-	150	°C
I _{T(AV)}	average on-state current	half sine wave; T _{mb} ≤ 133 °C	-	-	8	A
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 133 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	-	12.5	A
Static chara	acteristics					
I _{GT}	gate trigger current	V_D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>	-	2	15	mA

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Dynamic char	acteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 335 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); gate open circuit; exponential waveform; Fig. 12	-	300	-	V/µs

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	АНК
2	А	anode		G sym037
3	G	gate		Symosi
mb	A	mounting base; connected to anode		
			TO-220AB (SOT78)	

6. Ordering information

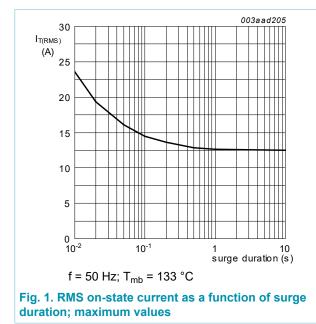
Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
BT151-500RT	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78			

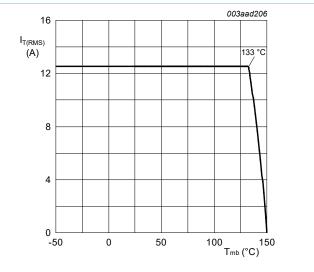
7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	500	V
V _{RRM}	repetitive peak reverse voltage		-	500	V
I _{T(AV)}	average on-state current	half sine wave; $T_{mb} \le 133 \text{ °C}$	-	8	А
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 133 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	12.5	A
I _{TSM}	non-repetitive peak on-	half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms	-	132	А
	state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4; Fig. 5</u>	-	120	A
l ² t	I ² t for fusing	t _p = 10 ms; SIN	-	72	A²s
dl _T /dt	rate of rise of on-state current	I _G = 30 mA	-	50	A/µs
I _{GM}	peak gate current		-	4	А
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	1	W
T _{stg}	storage temperature		-40	150	°C
T _j	junction temperature		-	150	°C

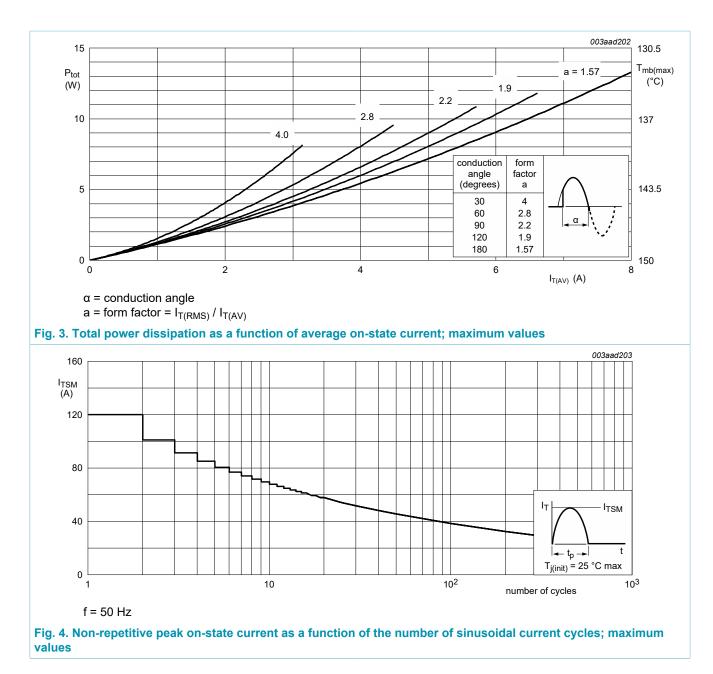






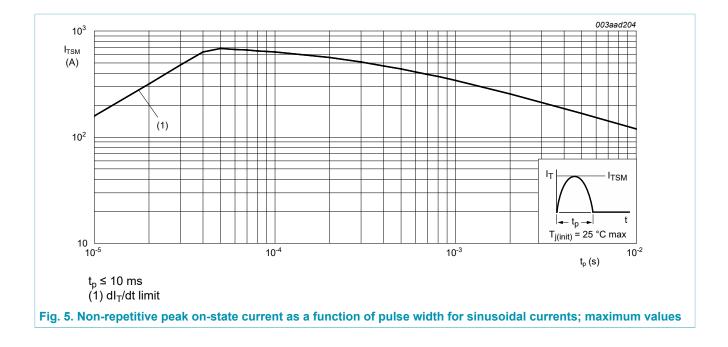
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8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. <u>6</u>	-	-	1.3	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W

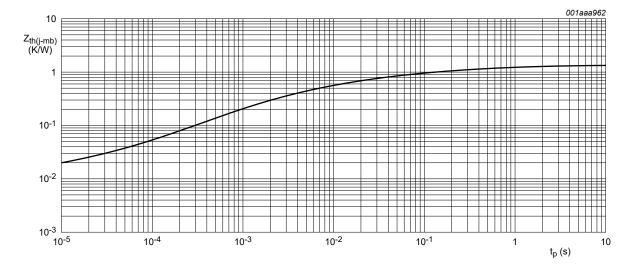
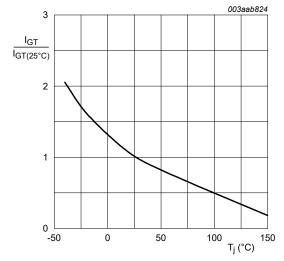


Fig. 6. Transient thermal impedance from junction to mounting base as a function of pulse width

9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>	-	2	15	mA
IL	latching current	V _D = 12 V; I _G = 0.1 A; T _j = 25 °C; <u>Fig. 8</u>	-	10	40	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	7	20	mA
V _T	on-state voltage	I _T = 23 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.4	1.75	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 11</u>	-	0.6	1	V
		V _D = 500 V; I _T = 0.1 A; T _j = 150 °C; <u>Fig. 11</u>	0.25	0.4	-	V
I _D	off-state current	V _D = 500 V; T _j = 150 °C	-	0.5	2.5	mA
I _R	reverse current	V _R = 500 V; T _j = 150 °C	-	0.5	2.5	mA
Dynamic ch	aracteristics		· · · · · ·			
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 335 V; T _j = 150 °C; (V_{DM} = 67% of V_{DRM}); gate open circuit; exponential waveform; Fig. 12	-	300	-	V/µs
t _{gt}	gate-controlled turn-on time	$\begin{split} I_{TM} &= 40 \text{ A}; V_{D} = 500 \text{V}; \text{I}_{G} = 0.1 \text{A}; \text{d} \text{I}_{G} \text{/} \\ \text{d} \text{t} &= 5 \text{A} / \mu \text{s}; \text{T}_{\text{j}} = 25 ^{\circ}\text{C} \end{split}$	-	2	-	μs
t _q	commutated turn-off time		-	70	-	μs





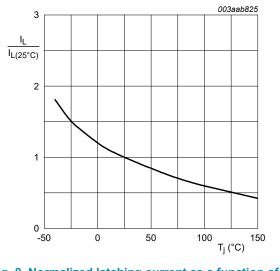
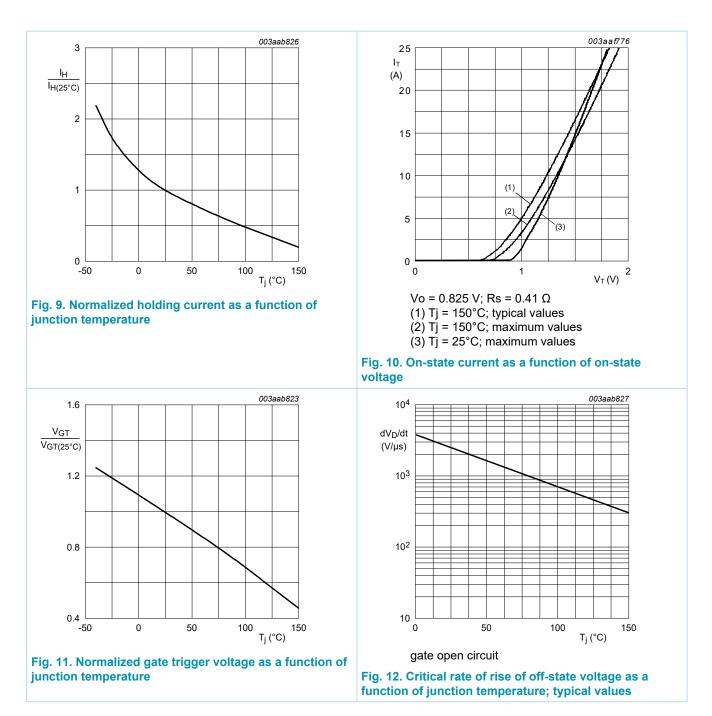


Fig. 8. Normalized latching current as a function of junction temperature

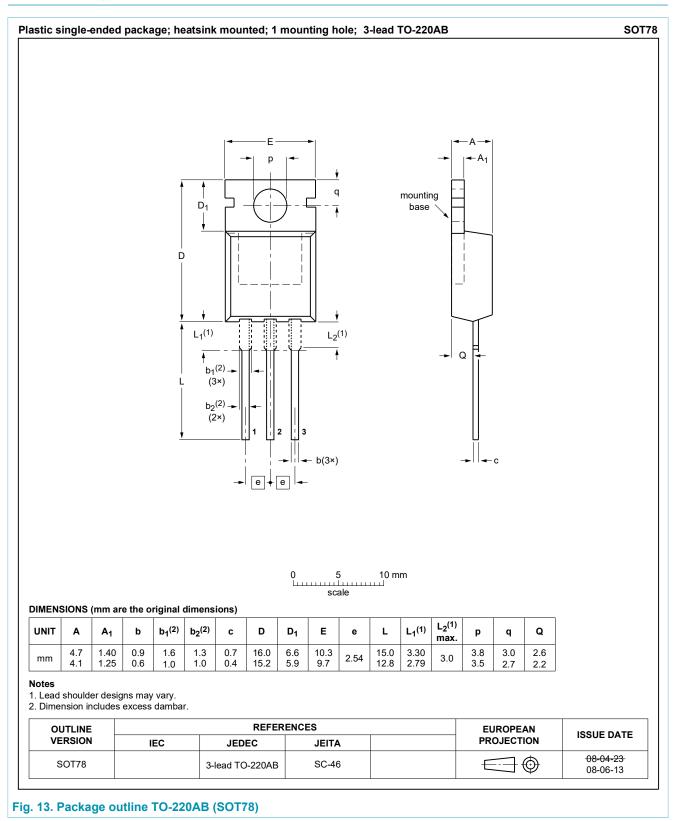
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10. Package outline



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11. Legal information

Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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